

### **DESCRIPTION**

The ESD5Z2.5/3.3/5.0/6.0/7.0/12 Series is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

The ESD5Z2.5/3.3/5.0/6.0/7.0/12 is available in SOD-523 Package.

### ORDERING INFORMATION

Package Type	Part Number		
	ESD5Z2.5		
SOD-523	ESD5Z3.3		
	ESD5Z5.0		
	ESD5Z6.0		
	ESD5Z7.0		
	ESD5Z12		
Note	SPQ: 3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

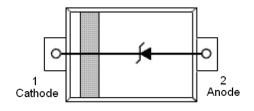
### **FEATURES**

- Small Body Outline Dimensions
- Low Body Height
- Stand-off Voltage: 2.5V 12V
- Peak Power up to 200Watts @ 8/20µs Pulse
- Low Leakage
- Response Time is Typically <1 ns</li>
- ESD Rating of Class 3 (> 16kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- IEC61000-4-4 Level 4 EFT Protection
- Available in SOD-523 Package

### **APPLICATIONS**

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

### PIN DESCRIPTION



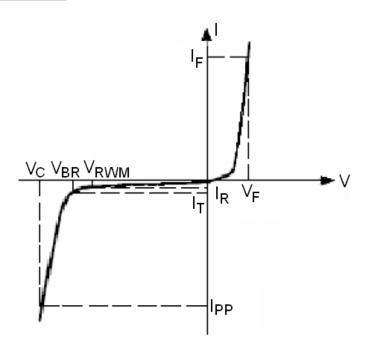
# ABSOLUTE MAXIMUM RATINGS

 $T_{amb} = 25^{\circ}C$ 

1 amb - 23 C			
P <sub>PP</sub> , Peak Pulse Power (t <sub>p</sub> = 8/20μs)		200W	
T <sub>L</sub> , Maximum Lead Temperature for Soldering During 10s		260°C	
T <sub>STG</sub> , Storage Temperature Range		-55°C ~ +150°C	
T <sub>OP</sub> , Operating Temperature Range		-40°C ~ +125°C	
T <sub>J</sub> , Maximum Junction Temperature		150°C	
IEC61000-4-2 (ESD)	Air discharge	±15kV	
	Contact discharge	±8kV	
IEC61000-4-4 (EFT)		40A	
ESD Voltage	Per Human Body Model	16kV	

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# ELECTRICAL PARAMETER



Symbol	Parameter	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
V <sub>RWM</sub>	Working Peak Reverse Voltage	
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>	
I <sub>T</sub>	Test Current	
V <sub>BR</sub>	Breakdown Voltage @ I⊤	
l <sub>F</sub>	Forward Current	
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>	

### **ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified. V<sub>F</sub> = 0.9V at I<sub>F</sub> = 10mA

Part Number	V <sub>RWM</sub> (V)	Ir(µA) @ Vrwm	V <sub>BR</sub> (V) @ I <sub>T</sub> NOTE1	lτ	V <sub>C</sub> (V) @ I <sub>PP</sub> =5A NOTE2	Vc(V)  @ Max I <sub>PP</sub> NOTE2	I <sub>PP</sub> (A) NOTE2	P <sub>PK</sub> (W)	C(pF)
	MAX	MAX	MIN	mA	TYP	MAX	MAX	MAX	TYP
ESD5Z2.5	2.5	6.0	4.0	1.0	6.5	10.9	11.0	120	145
ESD5Z3.3	3.3	1.0	5.0	1.0	8.4	14.1	11.2	158	105
ESD5Z5.0	5.0	1.0	6.2	1.0	11.6	18.6	9.4	174	80
ESD5Z6.0	6.0	1.0	6.8	1.0	12.4	20.5	8.8	181	70
ESD5Z7.0	7.0	1.0	7.5	1.0	13.5	22.7	8.8	200	65
ESD5Z12	12	1.0	13.5	1.0	17	25	9.6	240	55

NOTE1:  $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of 25°C .

NOTE2: Surge current waveform per Figure 1.

### TYPICAL CHARACTERISTICS

Figure 1. Pulse Waveform

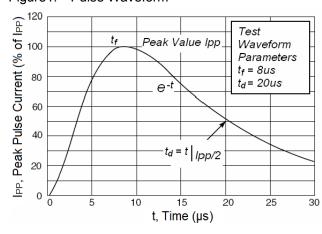
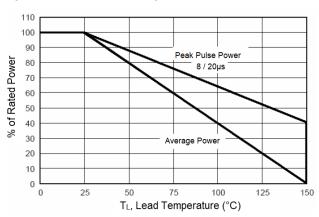


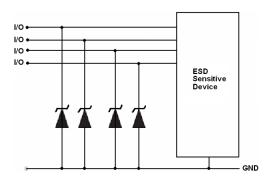
Figure 2. Power Derating



### **APPLICATION NOTE**

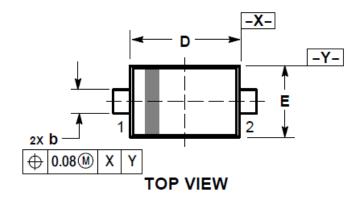
Electrostatic discharge (ESD) is a major cause of failure in electronic systems. Transient Voltage Suppressors (TVS) are an ideal choice for ESD protection. They are capable of clamping the incoming transient to a low enough level such that damage to the protected semiconductor is prevented.

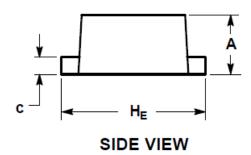
Surface mount TVS offer the best choice for minimal lead inductance. They serve as parallel protection elements, connected between the signal line to ground. As the transient rises above the operating voltage of the device, the TVS becomes a low impedance path diverting the transient current to ground. The ESD5Z2.5/3.3/5.0/6.0/7.0/12 is the ideal board level protection of ESD sensitive semiconductor components. The tiny SOD-523 package allows design flexibility in the design of high density boards where the space saving is at a premium. This enables to shorten the routing and contributes to hardening against ESD.

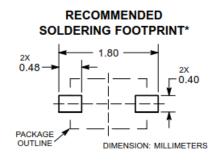


# PACKAGE INFORMATION

Dimension in SOD-523 Package (Unit: mm)







DIM	MIN	MAX		
А	0.50	0.70		
b	0.25	0.35		
С	0.07	0.20		
D	1.10	1.30		
Е	0.70	0.90		
HE	1.50	1.70		
L	0.30 REF			
L2	0.15	0.25		

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